# Performance analysis of thermoelectric generator using dc-dc converter with incremental conductance based maximum power point tracking

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5 6	Abstract:
7	Thermoelectric (TE) devices are regarded as alternative and environmentally friendly
8	for harvesting and recovering heat energy. Particularly, thermoelectric generators (TEGs)
9	are used for converting heat into electricity. One of the challenges behind TEG is that the
10	power generated is unstable and therefore needs proper power conditioning mechanism
11	before it is supplied to the load. Moreover, it is necessary to track the maximum power
12	point (MPP) at all times so that maximum power is always extracted from TEG devices.
13	The objective of this work is to analyse the performance of a dc-dc converter with
14	maximum power point tracking (MPPT) enabled by incremental conductance (IC) method.
15	The simplified model is used as the basis for TEG design while the dc-dc boost converter
16	is used for boosting and stabilising the power generated from TEG. The results of the IC
17	based MPPT approach have been compared with those of perturb and observe (P&O) based
18	MPPT from a previous researcher. The results indicate that the IC based MPPT approach
19	is able to track the MPP but with relatively lower efficiencies than the P&O based MPPT
20	method. The matching efficiency within a temperature range of_200°C- 300°C is in the
21	range of 99.92% - 99.95% for P&O and 99.46% - 99.97% for IC method. However IC
22	based MPPT method has higher voltage gain and converter efficiency than the P&O based
23	MPPT method. Therefore, dc-dc converters are able to improve the steady state
24	performance of TEG system as well as boosting the voltage to the desired level, hence
25	improving the overall performance of TEG system. Although both P&O and IC are two
26	classical algorithms that can be implemented to extract the maximum power from TEG,
27	the comparative study has established that P&O technique outperforms the IC method.
28	

29 *Keywords*: Thermoelectric power generation; dc-dc converter; TEG device; MPPT.

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#### 30 **1. Introduction**

31 The growth of industrialisation along with increased population has increased the world 32 energy demand. The indigenous fossil fuels besides being near their exhaustion have resulted into disastrous climatic changes such as greenhouse gas, especially due to 33 34 industrial and transportation pollutions [1]. A considerable amount of heat energy is wasted 35 mainly in industrial and transportation sector. In the French industry, 75% of the final 36 energy is used for thermal purposes such as furnaces, reactors, boilers and dryers. However, 37 around 30% of this heat is assumed to be wasted in form of discharged hot exhaust gas, cooling water and heated product [2]. Thus, the recovery of waste heat is capable of 38 39 contributing a considerable amount of energy for daily needs especially in the 40 transportation sector. The rapid development of power electronics technologies has 41 enabled the realization of high energy-efficient systems such as electric vehicles and thermoelectric (TE) technology [3]. Therefore, the waste heat can be recovered using a 42 43 thermoelectric generator (TEG) which is a device invented through thermoelectric 44 technology to convert heat into electric energy [4]. TEG modules offer low cost electricity, 45 and green energy technology without the use of moving parts or production of 46 environmentally deleterious wastes [5].

In recent years, there has been a remarkable advancement of TE devices and therefore their efficiencies are increasing greatly especially due to TE material and device geometrical improvements [6]. However, the efficiency of TEG is still low, being a subject of further research to improve the performance of TEG system. In addition to the research for new and advanced TE materials, the inter-dependency between TEG device and heat exchanger for heat recovery from exhaust gas and heat removal from coolant has been investigated to improve the performance of the devices [7].

54 Since low efficiency is the major challenge for TEG system, in a combined effort to 55 improve the performance of TEG device, it is necessary to extract the maximum power so 56 that the TEG device is operated near its full capacity. Hence, in addition to the application 57 of methods related to the development of TEG devices such as TE material improvement and geometrical enhancement, power conditioning methods can also be applied to ensure 58 59 that the maximum power is extracted from TEG system. Power conditioning method 60 includes impedance matching and application of dc-dc converters. The impedance 61 matching involves striking the balance between the total internal resistance of the TEG 62 system and external load resistance connected to the TEG system. For proper impedance 63 matching, the optimal electrical load should be equal to the internal resistance of the TEG module in order to ensure that the maximum power is transferred to the load [8]. However, 64 it is extremely difficult to achieve the balance between the internal resistance of TEG and 65 load without using special electronic devices. In this case it is hard to harvest the maximum 66 power from TEG device. Hence, a dc-dc converter with maximum power point tracker 67 68 (MPPT) is employed to achieve a stable voltage as well as the maximum power output [9]. MPPT techniques have been classified into conventional and intelligent techniques. The 69 70 conventional methods include incremental conductance (IC), perturb and observe (P&O), 71 and hill climbing methods [10]. The variant of these three methods have also been used in 72 literature for MPPT of solar PV systems. Intelligent techniques are sometimes referred to 73 as soft computing (SC) techniques and are known to have the ability and flexibility to solve 74 non-linear tasks and are suitable for handling different challenges arising out of adverse 75 environmental conditions like rapid changes in irradiance and temperature [11]. Although 76 both conventional and intelligent techniques have greatly been applied to photovoltaic (PV) 77 systems, few of them have been applied to TEG devices.

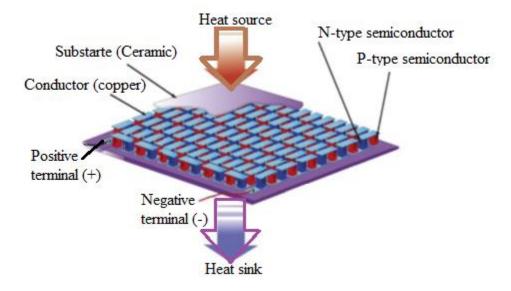
78 Several dc-dc converter topologies with MPPT have been proposed and analysed such as 79 dc-dc conversion network [12] and dc-dc converter with temperature sensor-based MPPT 80 [13]. It is observed that dc-dc converters are able to provide more stable output voltages and improve the performance of TEG system. The purpose of this work is to analyse the 81 performance of boost dc-dc converter with incremental conductance-based MPPT 82 algorithm on TEG system and clarify the effects of TEG main design parameters. Unlike 83 the indirect control MPPT methods that make use of proportional-integral (PI) controllers, 84 85 there by complicating the MPPT control circuit, in the direct MPPT control methods such as P&O and IC, the duty cycle is computed directly in the MPPT algorithm. The direct 86

- 87 control method is also advantageous because it simplifies the tracking structure and reduces
- the computation time, and less tuning effort is needed for the gain.
- 89

# 90 2. The structure and modelling of TEG device

A TEG unit is primarily composed of n-type and p-type semiconductors. A number of
TEG units are normally stacked to form a TEG module so as to produce the required power
as illustrated in Fig. 1.

94



95 96

Fig. 1. Illustration of the TEG setting for Power generation [14].

97 While choosing TEGs for application in varying conditions, it is necessary to select an 98 appropriate semiconductor with acceptable performance in the temperature range of that 99 condition [14]. The figure of merit (Z) is a parameter generally used to gauge the 100 performance of a TE material:

101

$$Z = \frac{\alpha_{p,n}^2 \sigma_{p,n}}{\lambda_{p,n}} \tag{1}$$

102 Where  $\alpha_{p,n}$  is the Seebeck coefficient of n-type or p-type material;  $\sigma_{p,n}$  is the electrical 103 conductivity of the material in p-type or n-type in Siemens per meter;  $\lambda_{p,n}$  is the thermal 104 conductivity.

With increased interest in TEG systems for different applications, research has been intensified, leading to the introduction of several advanced TEG models. This has been done through various modifications of the basic TEG module such as geometrical modifications, hybridizing of the materials used to form TEG, etc. As a result, tremendous improvements in the power output and efficiency have been achieved.

With the application of current through a thermoelectric element, thermal energy is 111 112 generated or absorbed at the junction due to Peltier effect. The exchange of Peltier heat between the semiconductor and metal (both the n- and p-type) is demonstrated in Fig. 2(a). 113 The Seebeck coefficient is proportional to the temperature and this effect is different at 114 115 different places along the TE material [17]. The thermoelectric element is a combination 116 of a series of many small Peltier junctions [as shown in dotted lines in Fig. 2(a)], each of 117 which separately produces or absorbs heat. This is the Thomson power developed per unit volume. In Thomson effect, the heat is evolved or absorbed when the current is passed 118 through a TE element with a temperature gradient. Therefore, this effect is equally 119 proportional to the temperature gradient and the electric current. 120

121 The Thomson coefficient  $\tau$  is expressed as

$$\tau = T \frac{d\alpha}{dT}$$
(2)

123 Where  $\alpha$  is the Seebeck coefficient; T is the average temperature. This equation indicates 124 that the Thomson coefficient must not be applied in situation where Seebeck coefficient is 125 constant and calculated with the average temperature.

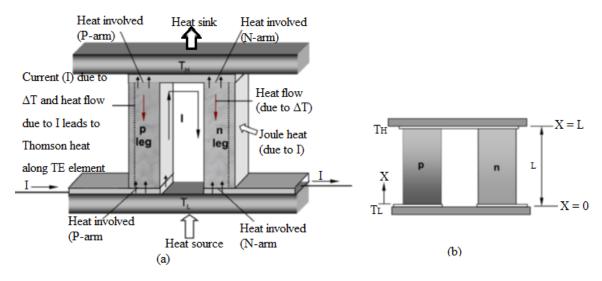




Fig. 2. The schematic view of a thermoelectric cooler [15].

128 Two major categories of thermoelectric models are: the simplified and the complex 129 models. The simplified models are based on a global balance of heat transfer and 130 thermoelectric effects (macro approach) i.e. some of the TE effects are kept constant while others are neglected. For example the Seebeck effect is kept constant, leading to the 131 132 Thomson effect to be zero or negligible [16]. Unlike the simplified models, in complex models the thermoelectric element behaviour is described more precisely with the use of 133 134 local energy balance equations because all thermoelectric effects are caused by coupling 135 between charge transport and heat transport and therefore the quantification of these transports can be evaluated using the mass, energy and entropy equations, forming rigorous 136 137 thermodynamic frameworks [15]. The simplest approach to model a TE element is to set up an overall thermal energy balance, assuming a symmetrical distribution of the Joule 138 139 effect between the cold and hot sides of the TE element. The Seebeck coefficient  $\alpha$ , the thermal conductivity k, and the electrical conductivity  $\sigma$  of the thermoelectric element are 140 kept constant in the material and estimated from the mean temperature  $\overline{T}$  of the hot and 141 142 cold sides at  $T_H$  and  $T_C$ , respectively.

143

144

 $\bar{T} = \frac{T_H + T_c}{2} \tag{3}$ 

145

This assumption is quite reliable in steady state as long as the Joule effect is not predominant. Other definitions can be considered from an evaluation of the temperature variation within the leg. It would allow calculating more precisely the average temperature. This is because the temperature variation is a posteriori known, i.e. the variations have to be justified through experimental observations. Based on these assumptions, global energy balance in the whole leg produces the following expressions:

#### 152 For TE Cooling (TEC)/TE Heating (TEH):

153 
$$Q_H = \bar{\alpha} I T_H - \bar{K} \Delta T + \frac{1}{2} \bar{R} I^2$$
(4)

$$Q_c = \bar{\alpha} I T_c - \bar{K} \Delta T - \frac{1}{2} \bar{R} I^2$$
(1)
(1)

155 For TEG:

156 
$$Q_H = \bar{\alpha} I T_H + \bar{K} \Delta T - \frac{1}{2} \bar{R} I^2$$
(6)

157 
$$Q_c = \bar{\alpha} I T_H + \bar{K} \Delta T + \frac{1}{2} \bar{R} I^2$$
(7)

158 Where

159 
$$\bar{R} = \frac{L}{\bar{\sigma}A}$$
 : Electrical resistance (8)

160 
$$\overline{K} = \frac{\overline{k}A}{L}$$
 : Thermal conductance (9)

161

163

162 The electrical power is the difference between the hot and cold thermal fluxes:

$$P = Q_H - Q_C \tag{10}$$

(12)

164 This gives:

165 
$$P = \bar{\alpha}I\Delta T + \bar{R}I^2, \text{ for TEC/TEH}$$
(11)

166 
$$P = \bar{\alpha} I \Delta T - \bar{R} I^2$$
, for TEG

167

168 In TEC and TEH modes, the coefficients of performance (COPs) are respectively given

169 by:
$$COP_c = \frac{Q_c}{P}$$
 and  $COP_H = \frac{Q_H}{P}$  (13)

170 The electrical efficiency in TEG mode is given by;

171 
$$\eta = \frac{P}{Q_H} \tag{14}$$

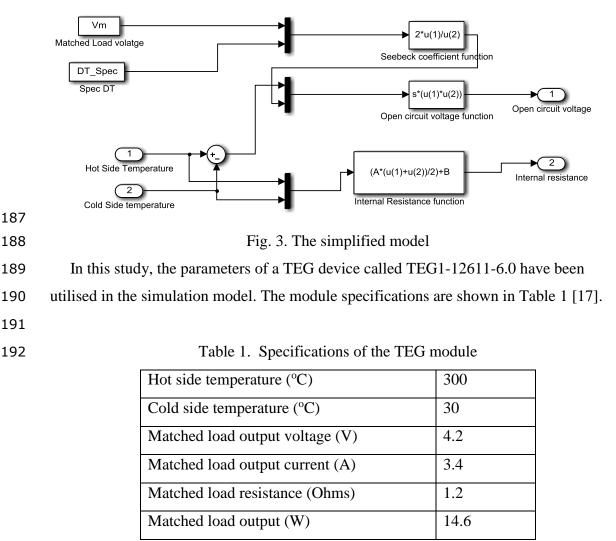
In the above equations, the Thomson effect is zero as the Seebeck coefficient is assumedconstant.

In the improved simplified model, as compared to the standard simplified model, the
Thomson effect is taken into account and assumed to be equitably distributed on both sides
of the semiconductor.

177 The second improvement is relative to the evaluation of the thermoelectric coefficient 178 as a function of temperature. The temperature used to evaluate each coefficient is defined 179 by distinguishing the volume phenomena in the leg (conduction, Joule and Thomson 180 effects) and the Seebeck effect taking place at the junction of two semiconductors. Thus 181 the mean temperature  $\overline{T}$  is used to evaluate the coefficients k,  $\sigma$ , and  $\tau$ .

182 The simplified TEG model can generate the voltage and internal resistance parameters 183 as the output. This is very important especially when modelling with dc-dc converters 184 which require voltage and resistance as input parameters for analysis of their performance. 185 Therefore, in this paper, the simplified model is used as the basis for designing the TEG.

186 Fig. 3 shows the simplified model.



193

# 194 **3. The dc-dc converter**

195

A classical boost converter can take a low voltage for example 10V, as input and step it up or boost it to high voltage say, to 15V. Fig. 4 shows a classical boost converter with a 10V source as its input voltage.

199

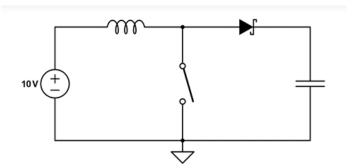
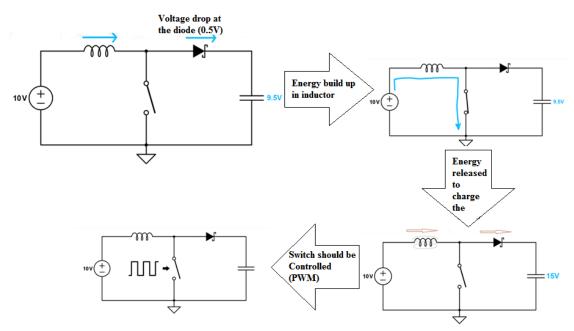


Fig. 4. A classical boost converter equivalent circuit

Fig. 5 shows how the boost converter operates to boost the voltage. When the switch is open, the output capacitor gets charged to 9.5V. So far, the voltage has dropped due to the current flow across the diode since it has some internal resistance. When the switch is closed, the diode prevents the capacitor from discharging, so the output voltage stays at 9.5V. But now there is a current path from the source through inductor and the switch to the ground.



209

210

Fig. 5. Functioning of a boost converter

The switch is closed for a fraction of a second just long enough to allow some current to flow through the inductor. This leads to the energy to be stored in the inductor in form of magnetic field. When the switch is opened and since the current in the inductor does not change instantly, the current has to flow through the inductor and the diode into the capacitor. So energy gets transferred from the inductor through the diode to the capacitor and the voltage increases. The boost converter has now boosted or stepped up the voltage.
So, since the switch is not supposed to be closed for a very long time, it should be controlled
with a high frequency PWM signal. Hence the use of PWM signal in dc-dc converters to
control the switch.

#### 220 **3.1 Power conditioning and efficiency improvement of TEG**

The voltage-current characteristics as well as power of a TEG device are non-linear and therefore it is quite necessary to recondition the power output of the TEG before it is supplied to the load. Several methods are reported which can be applied to stabilize the voltage and current generated from the TEG as well as the output power, thereby enhancing the performance of the whole TEG system. The first and straight forward technique is to use impedance matching whereby the usefulness of matching the TEG power output with the electrical load is demonstrated in the simulation and experimental work [18].

228 By enhancing the heat transfer within the TEG device, its performance can be improved. 229 The heat flux into the TEG can be increased by properly positioning the high temperature 230 heat pipes within the gas flow. The recovery of waste heat using TEG from a low carbon 231 vehicle revealed that a higher power output of 450W at a speed of 5000 rpm can be 232 achieved with the installation of TEG heat exchanger between the muffler and catalytic 233 converter [19]. Additionally, if the TEG heat exchanger is adjacent to the outlet of a 234 catalytic converter, the power output of 705W at 6000 rpm is obtained for a single sub 235 pipeline, resulting into a total of 1410 W for a dual pipeline system

Another method involves the adjustment of the boundary temperature and the number of TEG units. In this method, three ways are suggested to improve TEG power output: raising the hot-side temperature; lowering the cold-side temperature and increasing the quantity of modules [20]. An independent cooling system can be used to lower the temperature of the cold side. Alternatively, the hot-side temperature can also be increased but this is limited to a certain level. Equally, the number of TEG modules used in the system is also limited by some factors such as cost and space.

The application of dc-dc converter is another technique that can be used to improve the performance of TEG system. The dc-dc converter is an electronic circuit capable of converting from one source of direct current (DC) to another DC voltage. It is important in a situation where a higher voltage is needed from a lower voltage (boosting) or a low 247 voltage is needed from a higher voltage (bucking). It is also applied to regulate the voltage 248 from unregulated sources such as TEG devices, solar cells etc. therefore, several 249 configurations of dc-dc converters are available to suit different applications. Many of the 250 readily available dc-dc converters are designed to work under a (nearly) constant voltage 251 source and therefore their performance may not be as expected when connected to a variable current source like a TEG or PV system [21]. Therefore, the choice of a right 252 253 converter affects the optimum performance of the whole system. In this case a proper 254 criterion has to be followed to choose the best dc-dc converter. Table 2 presents the 255 summary of the qualities and the implications of applying different dc-dc converters to 256 TEG system.

Table 2. Summary of the qualities and implications of different dc – dc converters due to
their application on TEG systems: Modified from [22].

Converter	Features	Application	Advantage	Limitation
Boost	<ul> <li>Converts from a low voltage to higher voltage</li> <li>Load current smaller than the input current</li> <li>Most commonly used</li> <li>middle and low level in the conversion network</li> </ul>	• Suitable for TEG with unstable internal resistance and output voltage	• Precise and flexible conversion factor	• Requires a large Inductance to get high efficiency
Buck	<ul> <li>converts from a higher voltage to a lower voltage</li> <li>PWM controlled</li> </ul>	• Where a lower voltage level is needed to supply the load	• Precise and flexible conversion factor	<ul> <li>High voltage ripples at the output</li> <li>Higher flux density due to large size of inductance.</li> </ul>
Push-pull	<ul> <li>High level conversion of high power</li> <li>step-up and step-down tasks</li> <li>Multiple outputs due to transformer isolation</li> </ul>	<ul> <li>High Power Application (range of kWs)</li> <li>Fairly good efficiency</li> </ul>	<ul> <li>Less likely to cause saturation than in the fly-back converter,</li> <li>Hence smaller size</li> </ul>	<ul> <li>More complex</li> <li>MOSFETs must be able to handle twice the input voltage,</li> <li>Hence used for low voltage application</li> </ul>

Cu'k	Middle level conversion	• suitable for sensitive	• Stable input and	
	• continuous output current	environments	output terminal	
	• can boost or buck the		currents	
	voltage		• Easy to cancel	
	•		ripples (by	
			adjusting	
			inductors)1,	
			• Emit less RF	
			noise	
Buck-	• Increase and decrease the			
boost	output voltage			
	• load voltage is inverted			
Fly-back	• Increase or decrease the	• Where multiple	• No separate	• Very high peak
	output voltage	outputs are required	inductor is	currents
	• Transformer is used		needed since the	
	• Multiple output can be		transformer is	
	obtained		used for storage	
	• Output energy is stored as		• Cost effective	
	magnetic energy and		• Multiple outputs	
	released to the load later.		are possible.	

## 261 **3.2.** The maximum power point tracking (MPPT) system

The purpose of applying the MPPT algorithm is to ensure that at any temperature difference, the maximum power is obtained from TEG device. This is achieved by matching the TEG's MPP with the operating voltage and current of the MPPT controlledconverter.

The dc-dc converters with MPPT have generally found application in PV system but can also be applied in TEG system. The MPPT methods can be divided into two main groups: the first based on voltage feedback and the second based on regulating the generated power. The method based on voltage feedback works in such a way that a predetermined reference voltage is compared with TEG module voltage in a feedback loop [23]. The second method is based on regulating the generated power by sensing the PV/TEG module voltage and current to track the MPP. Perturb and Observe (P&O) and
incremental conductance (IC) are the examples of this method. The MPPT functionality is
normally integrated into the dc-dc converter to achieve higher power-extracting efficiency
[24].

276 The MPPT algorithm operates by sensing the current and voltage of the TEG. By using 277 the current and voltage, TEG power is calculated and compared with the present value of 278 MPP. Accordingly, the duty cycle of the converter is adjusted to match the MPP, thereby 279 forcing the converter to extract the maximum power. This is referred to as the direct duty 280 cycle MPPT control. The duty cycle is computed directly in the MPPT algorithm. The direct control method is advantageous because it simplifies the tracking structure and 281 282 reduces the computation time, and less tuning effort is needed for the gain. However, a proportional-integral (PI) or hysteresis controller can be used instead to adjust the duty 283 284 cycle of the converter. This makes the MPPT control circuit complicated and much effort 285 is needed to tune the PI gains while producing similar optimal results as the direct control 286 method.

#### **3.3.** The Perturb & Observe and Incremental Conductance methods

288 The P&O algorithm whose working principle is demonstrated in Fig. 6 introduces a 289 perturbation ( $\Phi$ ) in the operating voltage and current of TEG/PV array. As a result, the 290 change in the operating power is observed. The relative increase in the operating power 291 indicates that the converter is approaching the MPP. Similarly, during the succeeding 292 sampling cycle, the slope (direction) of perturbation is maintained whereas the reference current and voltage are further increased by  $\Phi$  value. Once the vicinity of MPP is reached, 293 with each new perturbation (with alternating sign polarity), the algorithm will go back and 294 295 forth around the MPP. Consequently, it does not reach exactly the MPP but it oscillates 296 around that point indefinitely [10].

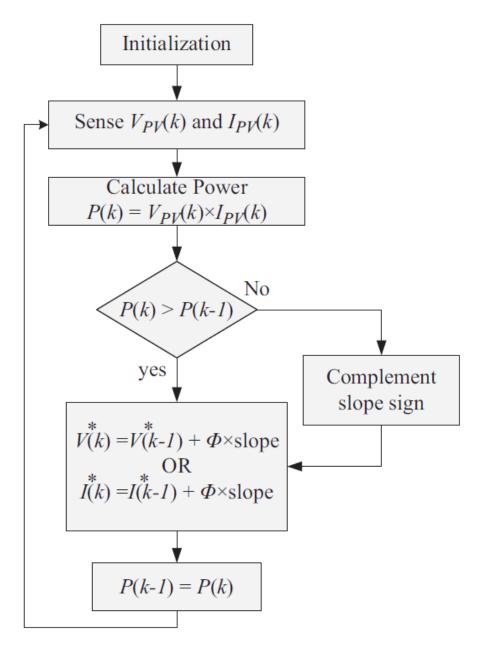




Fig. 6. Flow chart of conventional Perturb and Observe (P&O) method [10].

The IC method operates by incrementally comparing the ratio of derivative of conductance with the instantaneous conductance. This is due to the fact that at MPP, the derivative of power with respect to voltage (dP/dV) is zero, i.e.

303

304 
$$\frac{dP}{dV} = \frac{d(VI)}{dV} = I + V \frac{dI}{dV} = 0$$
 (15)

305 After re-arranging Eq. (15)

$$306 \qquad -\frac{I}{V} = \frac{dI}{dV} \cong \frac{\Delta I}{\Delta V} \tag{16}$$

Where I and V are the TEG output current and voltage;  $\Delta I$  and  $\Delta V$  are the increments of TEG output current and voltage, respectively. The basic rules for IC can be written as:

310 
$$\begin{cases} \frac{dI}{dV} = -\frac{I}{V}, & At MPP \\ \frac{dI}{dV} > -\frac{I}{V}, & Left of MPP \\ \frac{dI}{dV} < -\frac{I}{V}, & Right of MPP \end{cases}$$
(17)

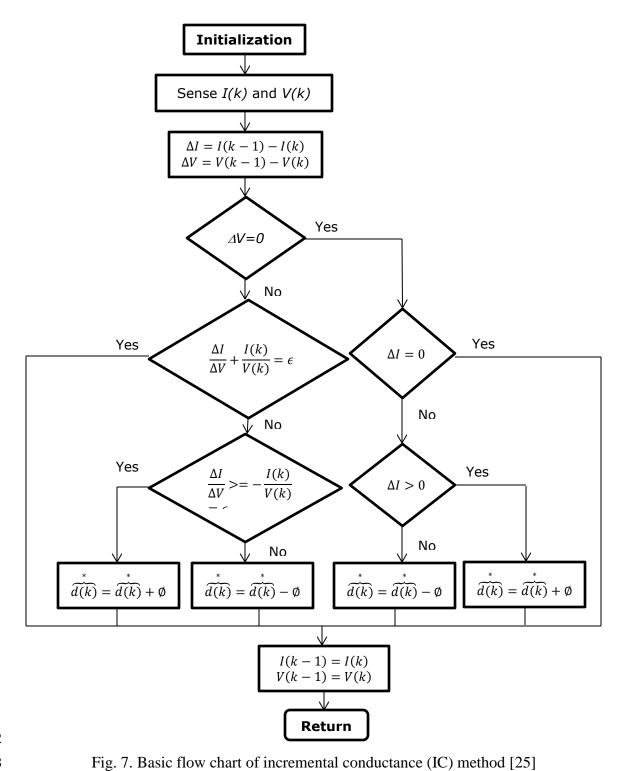
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312 It can be noticed that the MPP condition (dI/dV + I/V = 0) rarely exists in practical 313 application; hence, another alternative yet an effective way to utilize the IC is proposed by 314 a number of researchers [17]. The idea is to generate a marginal error  $\mathcal{E}$  using the 315 instantaneous conductance and the incremental conductance. Mathematically, it can be 316 written as:

317 
$$\frac{dI}{dV} + \frac{I}{V} = 0$$
 (18)

From Eq. (18), it can be seen that the value of  $\varepsilon$  is zero at MPP. Hence, based on the amount of  $\varepsilon$  and using the rules of Eq. (17), a basic flow chart for IC is depicted in Fig. 7.

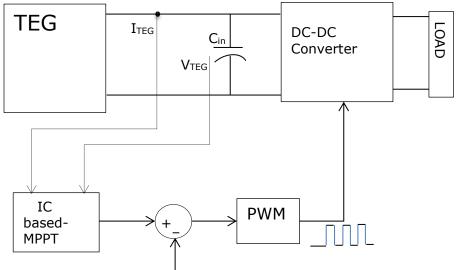
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- 321





# 326 **4.** The proposed TEG power conditioning system

The proposed TEG power conditioning circuit consists of four main components: the TEG, the dc-dc converter, MPPT and the PWM signal generator. Fig. 8 shows a block diagram of the proposed circuit.

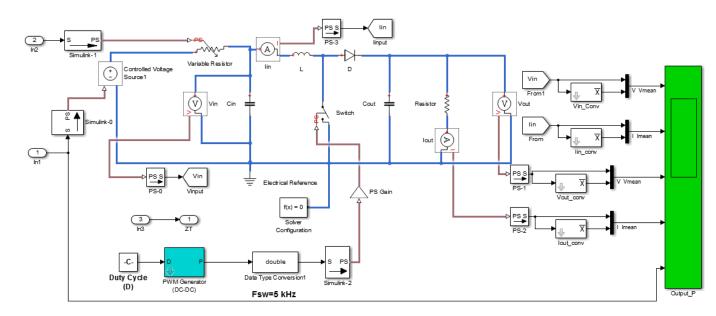


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Fig. 8. Block diagram of the proposed TEG power conditioning system

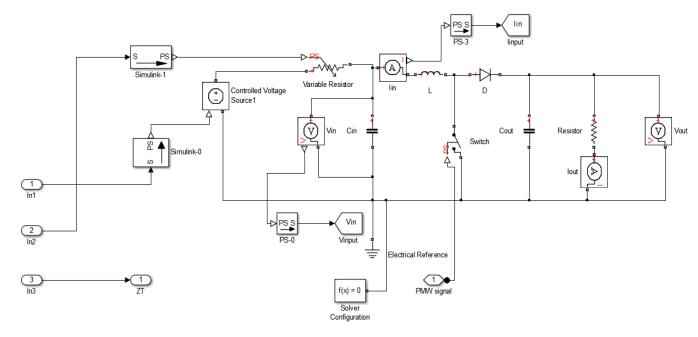
332 The boost converter circuit implemented with direct PWM signal is shown in Fig. 9a and

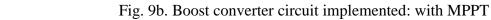
the boost converter circuit implemented with MPPT is given in Fig. 9b.



334 335

Fig. 9a. Boost converter circuit implemented: with direct PWM signal





# 339 5. Results and discussion

As indicated earlier, the modelling is performed in Simulink. So, Fig. 10 shows the

- 341 modelled circuit from which the results are obtained for analysis.
- 342

337

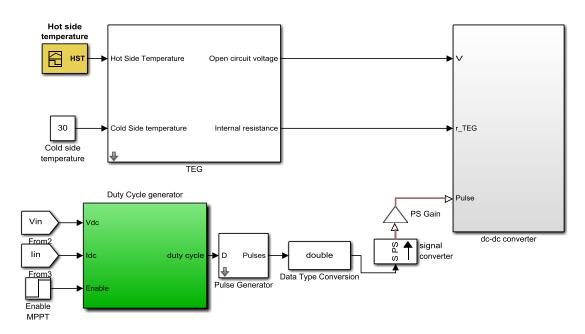
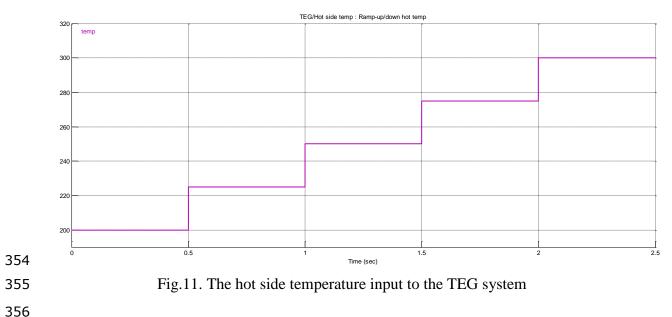




Fig. 10. The proposed TEG Power conditioning system modelled in Simulink

The cold side temperature is set as 30°C whereas hot side temperatures is set at 200°C, 225°C, 250°C, 275°C and 300°C in order to test the performance of the converter system at 200°C – 300°C temperature range. The hot side temperature input to the TEG system is shown in Fig. 11 in a ramp function. The simulated model is designed in such way that it is possible to change the number of TEG modules in series as shown in Fig. 12. Therefore, the results are shown with different number of TEG modules in series.

The results are presented with instantaneous and steady state values of voltage and power. In addition, the values of efficiencies of the MPPT and the converter are also reported and discussed.



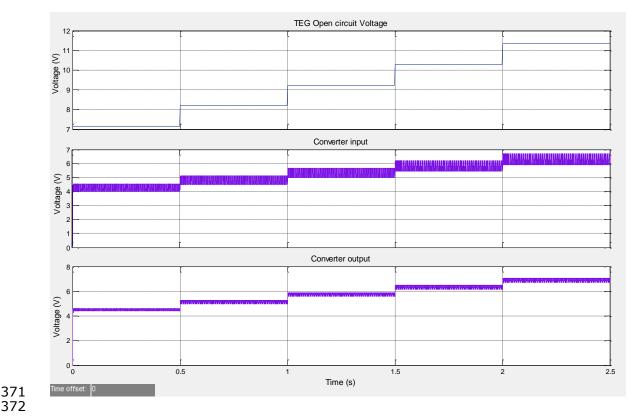
Punction Bloo	ck Parameters: 1	TEG		:
– Subsystem (ma	isk)			
– Parameters ––				
Matched Load	Voltage			
4.2				
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200				
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0.0028				
Rteg T-curve in	itercept			
0.56				
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	ОК	Cancel	Help	Apply

358

# Fig.12. TEG block parameter adjustment in the simulation model

359 Fig. 13 shows the instantaneous voltages of the system. Obviously the open circuit voltage is higher than any other voltage values. As seen from Fig. 13, the input voltage to 360 361 the converter is unstable; the level of instability is demonstrated by the size of the output 362 voltage trace. As observed from Fig. 13, the output voltage from the converter is relatively 363 stable and depending on the requirement, the voltage can also be boosted to higher value. In this case, the input temperature is a ramp function where the temperature is uniform at 364 365 each temperature level of 0.5 seconds. However, with a non-uniform temperature input to 366 the TEG system, the converter is equally capable of tracking the maximum power point. 367 This is demonstrated by the replication of the ramp temperature input as seen from the 368 output of the converter.

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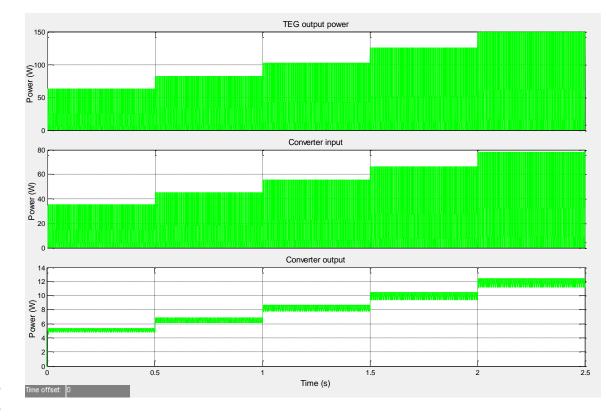


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Fig. 13. The instantaneous values of voltage for the systems

375 Fig. 14 shows the values of power from TEG as well as to and from the converter. The output power from TEG is a product of the open circuit voltage seen in Fig. 13 and the 376 377 highly unstable input current with a lot of harmonics. Similarly the input power to the 378 converter is a product of input voltage to the converter and the highly unstable input 379 current. Therefore, the input power to the converter is unstable due to the relatively 380 unstable voltage and the highly unstable current with several harmonics. As observed in Fig. 14, the output power is relatively stable with fewer harmonics. This is due to the 381 382 filtering done by the converter because of the presence of the filter circuit in form of a low 383 pass filter. With proper tuning of the filter circuit, the stability of the output can be improved. 384

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Fig. 14. Values of power from TEG as well as to and from the converter

At steady state, the values of voltage and power of the system are recorded by computing the average values at each hot side temperature level. The input and output voltages of the converter are demonstrated in Fig. 15 where input and output voltages of the converter are shown for the ten TEG modules in series. It is observed that at a temperature value of 200°C, the input voltage to the converter is about 41.18V which is boosted to 48.64V. Likewise, with a single TEG in series at the same temperature and an input voltage of 4.18V, the output voltage is stepped up to 4.5V as illustrated in Fig. 16.

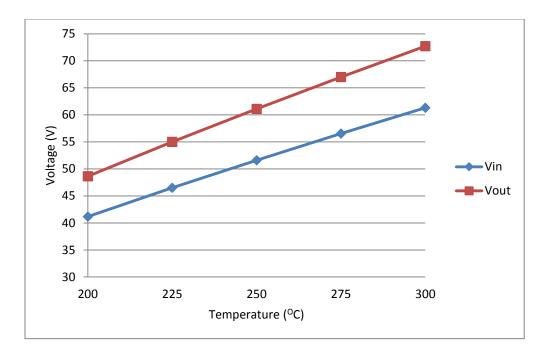
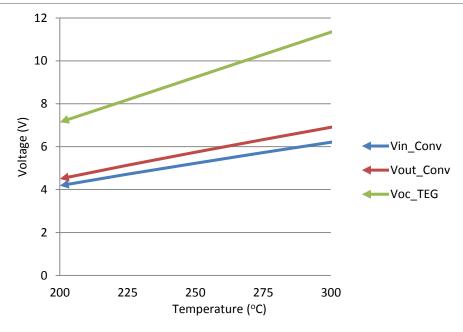




Fig. 15. Average input and output voltages of the converter at different temperatures for
 the ten TEG modules in series.

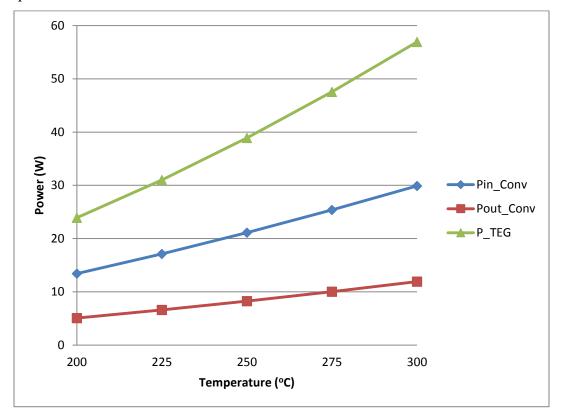


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405 406 407

Fig. 16. Average input, output voltages of the converter and open circuit voltages of TEG at different temperatures for a single TEG module.

Subsequently, the average power is shown in Fig. 17 for a single TEG module. As expected the average output power from TEG is higher than the input power to the converter. This is due to the high open circuit voltage  $V_{oc-TEG}$  seen in Fig. 16. In all cases, 411 the output power increases with the temperature. This is attributed to the increase in the 412 temperature difference (which is responsible for the Seebeck effect) as the hot side 413 temperature increases.



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Fig. 17. Average input and output powers of the converter and TEG output power at
different temperatures for a single TEG module.

417 **5.1 Verification of simulation results** 

418 The results of this study are compared with the those presented in literature [26]. In the 419 literature [26], the author studied a similar TEG/boost converter model with the same TEG 420 parameters but with P&O based MPPT method. Comparing with an open circuit voltage 421 of 7.2V at 200°C for the current study in Fig. 16 with that (about 7.2V at the same 422 temperature) of the previous study in Fig. 18a, the results of both cases agree. This means 423 there was no source of error in the TEG circuit. The difference in the results arises in the 424 input voltage to the converter. As observed in Fig. 16 and Fig. 17a, the input voltages to 425 the converter are 4.1V and 3.6V at 200°C for the current (IC based MPPT) and previous (P&O based MPPT) methods respectively. Similarly, the input power to the converter is 426 427 13.4W and 13.1W at 200°C as indicated in Fig. 17 and Fig. 18b for the IC and P&O based 428 MPPT methods respectively. The errors arise due to several factors; these include looping 429 errors in the MPPT algorithm leading to the simulation errors; component tolerances in the 430 MPPT circuit these affect the output parameters of the converter and MPPT circuitry. 431 Another cause of the difference in the results of both cases is the difference in the 432 computing capability of the MPPT algorithms where it can be observed that when the 433 voltage is compared alone, the IC based MPPT is more robust and less prone to errors than 434 P&O method because it is able to extract higher voltage than the P&O based MPPT 435 algorithm.

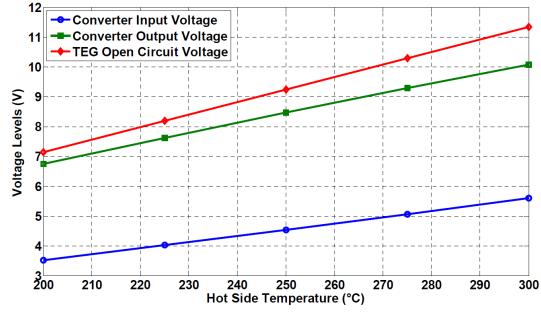
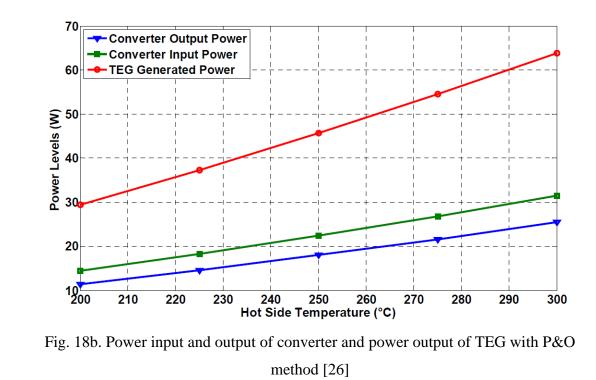


Fig. 18a. Converter input and output voltages and TEG open circuit voltages with P&O
method [26]

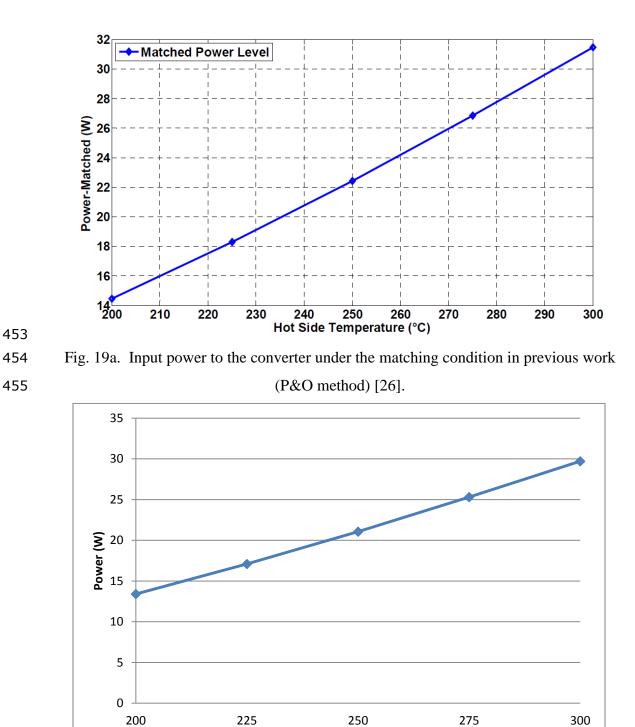
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#### 443 **5.2 Performance comparison of IC and P&O techniques**

Fig. 19a and Fig. 19b show the matched powers of P&O and IC based MPPT methods 444 respectively. At 200°C, the respective matched power outputs are 14.3W and 13.4W for 445 P&O and IC. From these power values at different temperatures, it is possible to compute 446 the MPPT matched efficiencies. Therefore, Fig. 20a and Fig. 20b show the MPPT matching 447 efficiencies for P&O and IC methods respectively. The matching efficiencies for the 200 448 °C – 300°C temperature range are 99.92% – 99.95% and 99.46 °C - 99.97% for P&O and 449 IC methods. Hence, P&O algorithm is slightly more efficient than the IC based MPPT 450 451 technique. It should also be noted that the MPPT matching efficiency of IC method 452 degrades as the hot side temperature increases as observed in Fig. 20b.



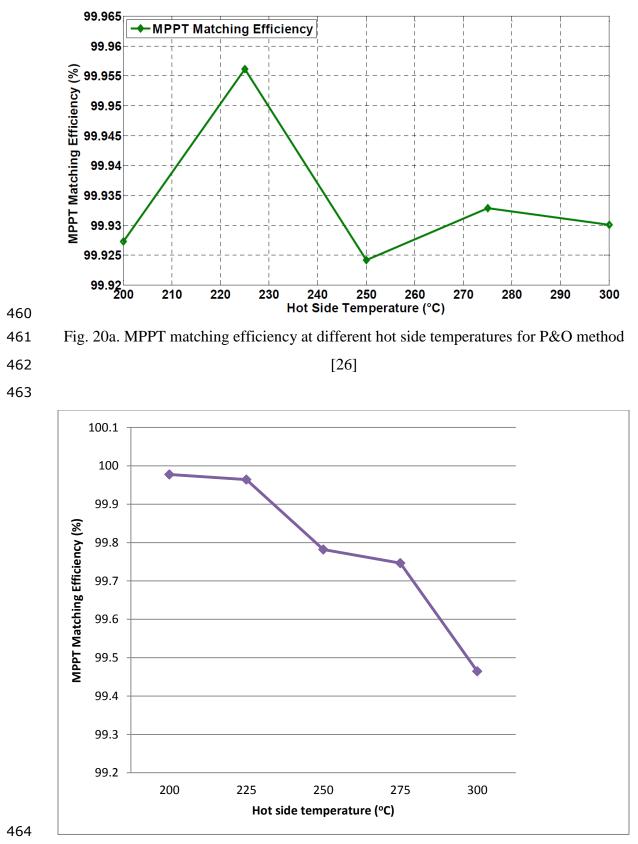


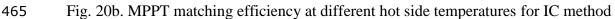
457 Fig. 19b. Input power to the converter under the matching condition in present work (IC

method)

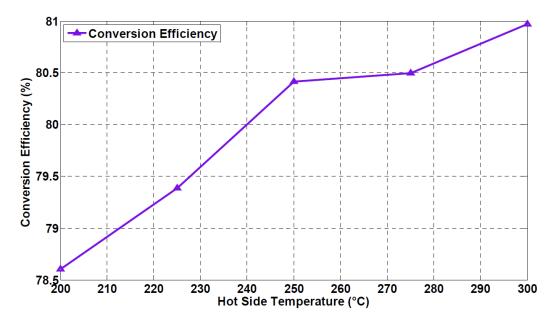
Hot side temperature (°C)

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The converter efficiencies for the P&O and IC based methods are shown in Fig. 21a and 21b in the ranges 78.52% – 81% and 87.1% – 88.7% respectively. It is observed that the corresponding converter efficiencies in the current study are higher than those in the previous study. This is attributed to the proper tuning of the converter circuitry. However, in both cases the conversion efficiency increases with the hot side temperature.



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Fig. 21a. Conversion efficiency of the converter at different hot side temperatures for

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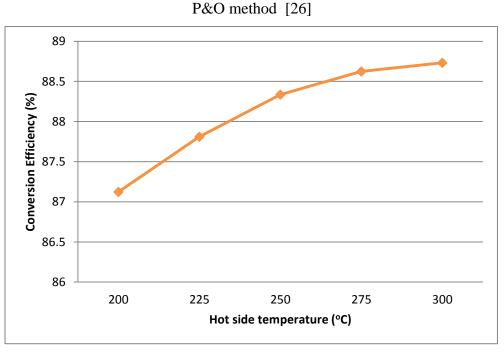


Fig. 21b. MPPT matching efficiency at different hot side temperatures for IC method

## 476 **5.3 Converter output without MPPT**

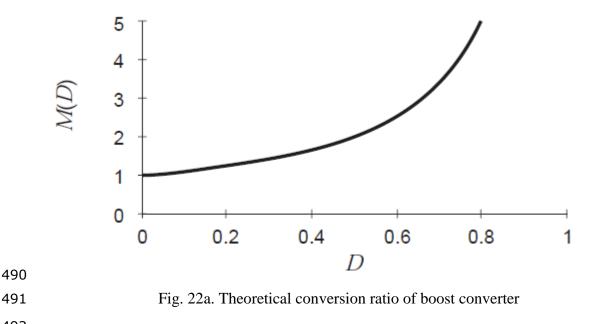
In this case, the converter switch is controlled with direct PWM signal as shown in Fig.
9a. Theoretically the conversion ratio M(D) is defined as the ratio of the dc output voltage
V to the dc input voltage V<sub>g</sub> under steady-state condition i.e.

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$$M(D) = \frac{V}{V_g} = \frac{1}{1 - D}$$
(19)

482 Where D is the duty cycle.

Ideally the conversion ratio of a boost converter increases with the duty cycle, and the ideal converter efficiency of 100% is obtained with M(D) = 1 when D = 0. This is illustrated in Fig. 22a. However, as M(D) tends to infinity, D tends to one. This is because at D = 1 the output voltage of the converter is zero or minimum while the current is maximum. Fig. 22b shows the conversion ratio obtained from the simulation. It is observed that the maximum efficiency is achieved at M(D) = 0.88 when D = 0. However, the conversion ratio M(D) has an increasing trend which is related to the theoretical one.



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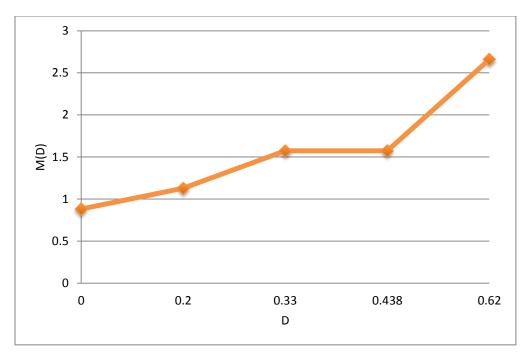


Fig. 22b. Conversion ratio of a boost converter obtained from the simulation.

Fig. 23 shows the output voltages of the converter at different values of D, it can be observed that at D =0, the highest values of output voltages are obtained and hence the converter efficiencies are computed at these values. The use of direct PWM signal can provide different voltage levels to the load at different duty cycles. This is useful when loads of different voltage levels are to be supplied one at a time.

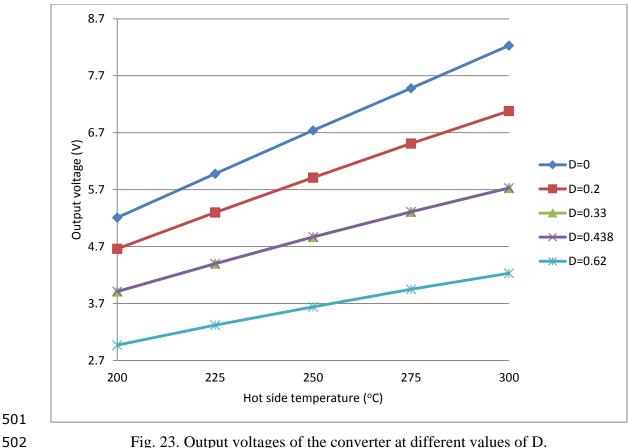


Fig. 23. Output voltages of the converter at different values of D.

#### 503 5.4 Variation of voltage with TEG modules

504 A number of scenarios are considered here with the number of TEG modules varied 505 from 1, 5 and 10 in order to investigate how the variation in the number of TEG modules 506 affects the output voltage of the TEG and converter. It can be observed from Fig. 24 that 507 there is a linear relationship between the converter input voltages and the hot side 508 temperature. Similarly, there is a direct relationship between the number of TEG modules 509 and converter input voltage i.e. as the number of TEG modules (TEG-Mn) is increased, the 510 voltage also increases.

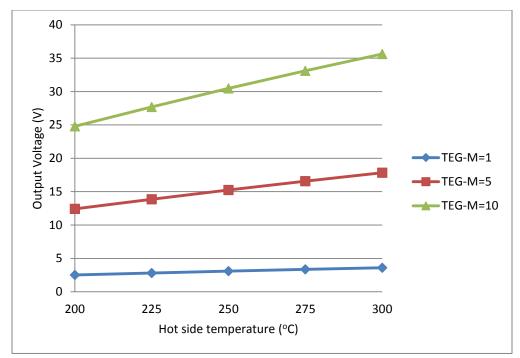


Fig. 24. The relationship between the converter input voltage and the hot side temperature.

511 512

#### 515 **6.** Conclusion

516 A proper power conditioning circuitry is necessary to stabilise and improve the 517 voltage and power generated from TEG before it is supplied to the load. In this work the 518 performance of a dc-dc converter with MPPT enabled by incremental conductance (IC) 519 method has been done. It has been observed that the IC based MPPT approach is able to 520 track the maximum power point but with relatively lower efficiencies than those of the 521 P&O based MPPT method. The matching efficiencies within a temperature range of 522 200°C- 300°C are in the ranges of 99.92% - 99.95% for P&O and 99.46% - 99.97% for IC 523 method. However IC based method has higher voltage gain and converter efficiency than 524 the P&O based MPPT method. Therefore, the dc-dc converters are able to improve the 525 steady state performance of TEG system as well as boosting the voltage to the desired level, 526 hence improving the overall performance of TEG system. Although both P&O and IC are 527 two classical algorithms that can be implemented to extract maximum power from TEG, the comparative study has established that P&O technique outperforms the IC method. 528

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